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# The interaction of two-dimensional $\alpha$ - and $\beta$ -phosphorus carbide with environmental molecules: a DFT study†

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The recently fabricated two-dimensional phosphorus carbide (PC) has been proposed for application in different nanodevices such as nanoantennas and field-effect transistors. However, the effect of ambient molecules on the properties of PC and, hence, the productivity of PC-based devices is still unknown. Herein a first-principles investigation is performed to study the most structurally stable  $\alpha$ - and  $\beta$ -PC allotropes upon their interaction with environmental molecules, including  $\text{NH}_3$ ,  $\text{NO}$ ,  $\text{NO}_2$ ,  $\text{H}_2\text{O}$ , and  $\text{O}_2$ . It is predicted that  $\text{NH}_3$ ,  $\text{H}_2\text{O}$ , and  $\text{O}_2$  are physisorbed on  $\alpha$ - and  $\beta$ -PC while  $\text{NO}$  and  $\text{NO}_2$  may easily form a covalent bond with the PC. Importantly,  $\text{NO}$  and  $\text{NO}_2$  possess low adsorption energies on PC which compared to these on graphene and phosphorene. Moreover, both molecules are strong acceptors to PC with a giant charge transfer of  $\sim 1 e$  per molecule. For all the considered molecules PC is found to be more sensitive compared to graphene and phosphorene. The present work provides useful insight into the effects of environmental molecules on the structure and electronic properties of  $\alpha$ - and  $\beta$ -PC, which may be important for their manufacturing, storage, and application in gas sensors and electronic devices.

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## Introduction

Despite great breakthroughs in the synthesis and characterization of 2D materials,<sup>1–5</sup> commercial applications of these materials on the global stage remain challenging. Due to their high surface-to-volume ratio, ultrathin thickness, and weak electronic screening, most 2D materials possess high chemical activity, which adversely affects their structural stability and properties under the exposure of environmental conditions.<sup>6–18</sup> The number of experimentally and theoretically discovered 2D materials is constantly growing. For example, in the last few years, a family of group V 2D materials called pnictogens which are phosphorene, antimonene, arsenene, and bismuthene has been discovered. Due to their buckled structure, 2D pnictogens actively interact with external adsorbates, which, however, can also affect their structure integrity and electronic and optical properties.<sup>19–22</sup> On the other hand, it is also known that a promoted interaction of 2D materials with environmental atoms and molecules allow their use in manufacturing of sensitive, highly selective, and environmentally stable gas detecting and storage devices.<sup>23–26</sup>

Recently, there has been a great demand for the investigation of 2D hybrid structures that successfully combine the best properties of their individual components.<sup>27–29</sup> A notable example of a hybrid structure is a monolayer boron carbide ( $\text{BC}$ )<sup>30–32</sup> – a mixture of carbon and boron atoms. This material has been found to be an efficient collector of toxic gases.<sup>33</sup> Other new exotic 2D hybrids are nitrophosphorene<sup>34</sup> and  $\text{GeP}_3$  monolayers.<sup>35,36</sup> Several modifications of nitrophosphorene have been found to be semiconductors with a wide and either direct or indirect band gap.<sup>29</sup> In turn,  $\text{GeP}_3$  monolayer has a small indirect band gap of 0.55 eV and high electron and hole mobilities.<sup>35</sup>

Graphene<sup>17</sup> and graphene-based hybrids such as  $\text{C}_2\text{N}$  and  $\text{C}_3\text{N}_4$  show high catalytic activity towards the CO and  $\text{O}_2$  molecules and possess high potential as CO oxidation catalyst with relatively low energy barriers.<sup>37</sup> Despite the unique structure and properties of the above mentioned 2D hybrids, the most attention is currently being paid to 2D phosphorus carbide (PC), a compound analogue of graphene and phosphorene.<sup>28,38,39</sup>

The PC has several allotropes which can be metallic, semi-metallic with an anisotropic Dirac cone, or direct band gap semiconductor.<sup>38</sup> Among these allotropes  $\alpha$ - and  $\beta$ -PC show the highest structural stability. It has already been shown that PC is a very promising candidate for application in optoelectronics.<sup>39</sup> Another study has reported on the high-performance PC-based field-effect transistor with extremely high hole mobility.<sup>28</sup> Due to the efficient excitation of hybrid plasmon mode at deep

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subwavelength-scale in the nanostructured PC layer, it has been proposed for applications in biosensors, single-photon source, nanoantenna, and subwavelength resolution imaging.<sup>27</sup>

Based on previous works where graphene reported as a structurally stable to the negative environmental effects<sup>40</sup> and considering the extremely high sensitivity of phosphorene to external molecules<sup>21,41,42</sup> it is necessary to obtain systematic knowledge on the interaction of environmental molecules and gases with 2D PC.

In this work, first-principles calculations were performed to study the interaction of semiconductor  $\alpha$ - and  $\beta$ -PC allotropes with environmental molecules such as  $\text{NH}_3$ ,  $\text{NO}$ ,  $\text{NO}_2$ ,  $\text{H}_2\text{O}$ , and  $\text{O}_2$ . Particularly, the geometry and energetics, charge transfer ability, band structure, and workfunction of the considered PC allotropes with these molecules were investigated. Superior chemical activities of  $\alpha$ - and  $\beta$ -PC allotropes over graphene and phosphorene demonstrate a promising application of the PC in ambient gas detections.

## Computational details

The first-principles calculations based on the spin-polarized density functional theory were implemented *via* the Vienna *ab initio* simulation package (VASP).<sup>43</sup> For the analysis of non-covalent chemical functionalization of phosphorus carbide (PC) by small molecules, a well-proven generalized gradient approximation (GGA) with the Perdew–Burke–Ernzerhof functional (PBE)<sup>44</sup> supplemented by the van der Waals-corrected functional with Becke88 optimization was used. The geometry of the molecules was completely optimized until the total energy and atomic forces become less than  $10^{-8}$  eV and  $10^{-3}$  eV  $\text{\AA}^{-1}$ . A plane wave cut-off of 400 eV and a  $6 \times 6 \times 1$   $k$ -mesh grid was adopted. To avoid the interaction with spurious replica images, the thickness of the vacuum region was greater than 15  $\text{\AA}$ . The studied structures which are  $\alpha$ - and  $\beta$ -PC named according to the classification introduced in the pioneer work predicted these materials.<sup>38</sup> The optimized unicells of the considered  $\alpha$ - and  $\beta$ -PC are shown in Fig. 1. The calculated lattice constants of  $\alpha$ - and  $\beta$ -PC considered in this work were  $a = 8.563$   $\text{\AA}$  and  $b = 2.870$   $\text{\AA}$  and  $a = 4.759$  and  $b = 2.950$ , respectively. Our calculated results are in good agreement with the previously reported ones.<sup>38,45</sup> Despite the band gap size is usually underestimated in PBE GGA calculations, it has been found that the PBE GGA method predicts qualitatively similar band structures of  $\alpha$ - and  $\beta$ -PC to calculated ones using more accurate hybrid functional.<sup>38</sup> To compromise computational efficiency and accuracy, results here were obtained using the PBE GGA approach.

The adsorption energy  $E_a$  of a molecule on PC were calculated as

$$E_a = E_{\text{PC+mol}} - E_{\text{PC}} - E_{\text{mol}} \quad (1)$$

where  $E_{\text{PC+mol}}$ ,  $E_{\text{PC}}$ , and  $E_{\text{mol}}$  are the energies of a molecule-adsorbed PC, an isolated PC, and an isolated molecule, respectively.

The Bader analysis<sup>46</sup> was used to estimate the charge transfer between the PC surface and small molecules. The workfunction WF which is the minimum energy required to

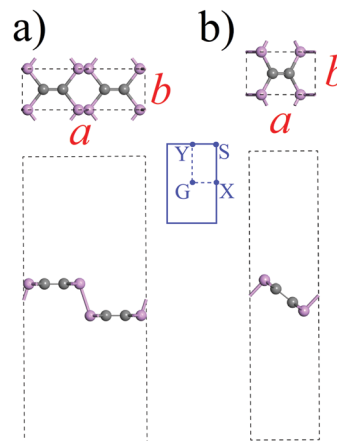


Fig. 1 The optimized unicells of (a)  $\alpha$ - and (b)  $\beta$ -PC and the  $K$ -path.

remove an electron from the surface of a solid was calculated as follows

$$\text{WF} = V_{\infty} - E_{\text{Fermi}} \quad (2)$$

Here  $V_{\infty}$  and  $E_{\text{Fermi}}$  represent the electrostatic potential of an electron at points remote from the surface and at the Fermi level, respectively.<sup>47</sup>

## Results and discussion

This study presents the analysis of the adsorption of  $\text{NH}_3$ ,  $\text{NO}$ ,  $\text{NO}_2$ ,  $\text{H}_2\text{O}$ , and  $\text{O}_2$  molecules on the surface of  $\alpha$ - and  $\beta$ -PC. The lowest-energy configuration for each molecule was determined by examination of their possible positions on the highly symmetric sites of  $\alpha$ - and  $\beta$ -PC surface, including both above the puckered hexagon and the zigzag trough with the molecules being aligned either parallel or perpendicular to the surface.

The data on the adsorption energy  $E_a$ , the charge transfer  $\Delta q$  from the molecule to the  $\alpha$ - and  $\beta$ -PC surface, and the distance  $d$  from the molecule to the  $\alpha$ - and  $\beta$ -PC surface for the lowest-energy configuration for each molecule is collected in Table 1. Several other examined configurations of the considered molecules on  $\alpha$ - and  $\beta$ -PC with the comparably low adsorption energy are shown in Fig. S1–S5 (see ESI<sup>†</sup>). The calculated values of the band gap size and workfunction of the pure and molecule-adsorbed  $\alpha$ - and  $\beta$ -PC surfaces are collected in Table 2. It is worth noting that the workfunction of pure  $\alpha$ - and  $\beta$ -PC is 4.87 and 4.95 eV, respectively, which is larger than that of graphene (4.33 eV)<sup>48</sup> while slightly less than that of phosphorene (5.04–5.16 eV).<sup>49</sup>

### $\text{NH}_3$ adsorption

Fig. 2a and c (left panels) show the lowest-energy atomic geometries of the  $\text{NH}_3$  molecule on the  $\alpha$ - and  $\beta$ -PC surface, respectively. For the  $\alpha$ -PC one, the  $\text{NH}_3$  molecule is located at  $d = 2.91$   $\text{\AA}$  with the N atom above the center of the hollow hexagon and the three H atoms directed away from the surface. The adsorption energy  $E_a$  is  $-0.29$  eV and the lengths of all the three N–H bonds are equal to 1.02  $\text{\AA}$ , comparable to the value (1.01  $\text{\AA}$ ) of a free  $\text{NH}_3$  gas molecule. In case of  $\beta$ -PC, the  $\text{NH}_3$

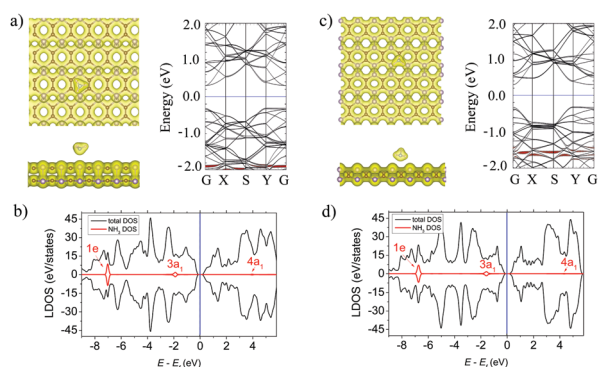


**Table 1** The adsorption energy  $E_a$ , the distance  $d$  from the molecule to the  $\alpha$ - and  $\beta$ -PC surface, and the amount of the charge  $\Delta q$  transferred from the molecule to the  $\alpha$ - and  $\beta$ -PC surface for the lowest-energy configuration for each molecule

Material		NH <sub>3</sub>	NO	NO <sub>2</sub>	H <sub>2</sub> O	O <sub>2</sub>
$\alpha$ -PC	$E_a$ , eV	-0.29	-0.36	-0.73	-0.24	-0.59
	$d$ , Å	2.91	2.14	1.67	1.77	2.87
	$\Delta q$ , e (role)	-0.029 (donor)	0.220 (acceptor)	1.023 (strong acceptor)	0.038 (acceptor)	0.075 (acceptor)
$\beta$ -PC	$E_a$ , eV	-0.30	-0.06	-0.59	-0.31	-0.18
	$\Delta d$ , Å	2.29	2.72	1.38	2.92	2.21
	$\Delta q$ , e (role)	-0.013 (donor)	-0.058 (donor)	1.013 (strong acceptor)	0.026 (acceptor)	0.067 (acceptor)
Graphene <sup>50,51</sup>	$E_a$ , eV	-0.03	-0.29	-0.67	-0.27	-0.04
Phosphorene <sup>20,22,49</sup>	$E_a$ , eV	-0.18	-0.32	-0.5	-0.14	-0.27

**Table 2** The workfunction WF and the fundamental band gap size  $E_g$  of pure and molecule-adsorbed  $\alpha$ - and  $\beta$ -PC

Material	$\alpha$ -PC		$\beta$ -PC	
	$E_g$ , eV	WF, eV	$E_g$ , eV	WF, eV
Pure	0.59	4.87	0.62	4.95
NH <sub>3</sub>	0.62	4.74	0.62	4.85
NO	0.53	4.63	0.62	4.84
NO <sub>2</sub>	0.66	5.07	0.66	4.61
H <sub>2</sub> O	0.62	4.87	0.62	5.13
O <sub>2</sub>	0.62	4.96	0.61	4.98



**Fig. 2** (a) Left panel: The top and side views of the lowest-energy configuration integrated with the total electron density plots for NH<sub>3</sub>-adsorbed  $\alpha$ -PC. Right panel: The band structure of NH<sub>3</sub>-adsorbed  $\alpha$ -PC. (b) The LDOS of NH<sub>3</sub>-adsorbed  $\alpha$ -PC. (c) Left panel: The top and side views of the lowest-energy configuration integrated with the total electron density plots for NH<sub>3</sub>-adsorbed  $\beta$ -PC. Right panel: The band structure of NH<sub>3</sub>-adsorbed  $\beta$ -PC. (d) The LDOS of NH<sub>3</sub>-adsorbed  $\beta$ -PC. The blue line shows the Fermi level. The isosurface value is set to 0.05 e Å<sup>-3</sup>. The bands and DOS coloured in red correspond to the NH<sub>3</sub> molecule.

molecule is located at  $d = 2.29$  Å with the N atom above the C–C bond, one H atom directed out from the surface, and the other two H atoms are almost parallel to the surface. The  $E_a$  is  $-0.30$  eV and the lengths of the N–H bonds are also 1.02 Å. It should be noted, that  $E_a$  of the NH<sub>3</sub> molecule on both  $\alpha$ - and  $\beta$ -PC is  $\sim 10$  times more negative than that of graphene ( $E_a = -0.03$  eV)<sup>50</sup> and about 2 times than that of phosphorene ( $E_a = -0.18$  eV).<sup>22,51</sup>

Fig. 2a and c (left panels) show the total electron density for the NH<sub>3</sub> molecule on the  $\alpha$ - and  $\beta$ -PC surface, respectively. In both cases, the zero-electron density at the interface region

between the molecule and the surface suggests the NH<sub>3</sub> molecule does not form a covalent bond with PC upon adsorption. The Bader analysis predicted that the NH<sub>3</sub> molecule is a donor for  $\alpha$ - and  $\beta$ -PC, similarly to graphene<sup>50</sup> and phosphorene.<sup>21,51</sup> A small charge transfer of 0.029 and 0.013  $e$  per molecule was revealed from the NH<sub>3</sub> molecule to the  $\alpha$ - and  $\beta$ -PC surfaces, respectively.

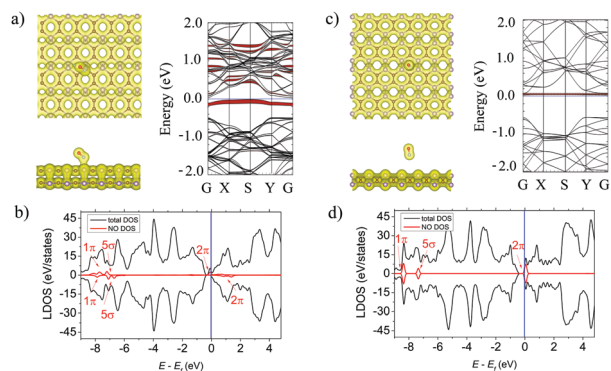
Fig. 2b and d show the local density of states (LDOS) plots for the NH<sub>3</sub> molecule adsorbed on  $\alpha$ - and  $\beta$ -PC. In both cases, the 1e state is significantly below the Fermi level while the non-bonding 3a<sub>1</sub> state appears in the vicinity of the valence band maximum (VBM), which is also seen in the band structure plots (Fig. 2a and c, right panel). However, the band structure analysis revealed no significant changes in the band's alignment after the NH<sub>3</sub> adsorption on  $\alpha$ - and  $\beta$ -PC. Therefore, the fundamental band gap only slightly increases from 0.59 to 0.62 eV for  $\alpha$ -PC and remains unchanged for  $\beta$ -PC (Table 2). In addition, adsorption of the NH<sub>3</sub> molecule leads to a slight decrease of the workfunction of  $\alpha$ -PC (from 4.87 to 4.74 eV) and  $\beta$ -PC (from 4.95 to 4.85 eV).

### NO adsorption

As shown in Fig. 3a (left panel) the NO molecule is tilted to the  $\alpha$ -PC surface and is located above the C–P bond at  $d = 2.14$  Å. The N–O bond length of the adsorbed molecule is 1.18 Å which is comparable to that of a free NO molecule (1.16 Å). The  $E_a$  of the NO molecule on  $\alpha$ -PC is  $-0.36$  eV which is about 12 times more than that of graphene ( $E_a = -0.03$  eV)<sup>50</sup> and almost similar to the one of phosphorene ( $E_a = -0.32$  eV).<sup>22,42</sup> For the  $\beta$ -PC surface, the NO molecule is located at  $d = 2.72$  Å above the center of the hollow hexagon and the N–O bond is almost perpendicular the surface. The bond length of the adsorbed NO molecule is 1.16 Å, which slightly larger compared to that of a free NO gas molecule (1.01 Å). The  $E_a = -0.06$  eV in this case is about 5 times less than that of graphene ( $E_a = -0.29$  eV)<sup>50</sup> and that of phosphorene ( $E_a = -0.32$  eV).<sup>22,42</sup>

The total electron density plot for the  $\alpha$ -PC surface adsorbed with the NO molecule (Fig. 3a, left panel) suggests a strong interaction of the molecule and the surface. The formation of a covalent bond between the molecule and the nearest P atom is found. A zero-electron density at the interface region between the NO molecule and the  $\beta$ -PC surface in Fig. 3c, left panel





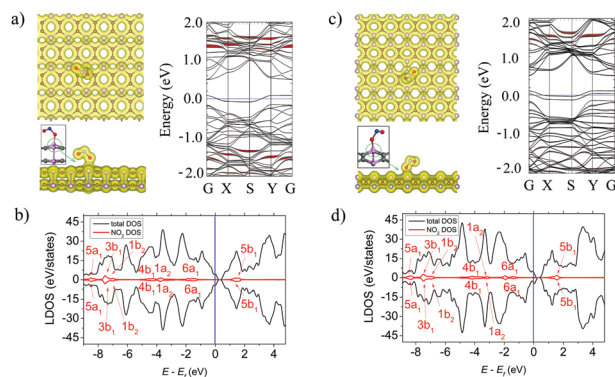
**Fig. 3** (a) Left panel: The top and side views of the lowest-energy configuration integrated with the total electron density plots for NO-adsorbed  $\alpha$ -PC. Right panel: The band structure of NO-adsorbed  $\alpha$ -PC. (b) The LDOS of NO-adsorbed  $\alpha$ -PC. (c) Left panel: The top and side views of the lowest-energy configuration integrated with the total electron density plots for NO-adsorbed  $\beta$ -PC. Right panel: The band structure of NO-adsorbed  $\beta$ -PC. (d) The LDOS of NO-adsorbed  $\beta$ -PC. The blue line shows the Fermi level. The isosurface value is set to  $0.05 e \text{ \AA}^{-3}$ . The bands and DOS coloured in red correspond to the NO molecule.

implies non-covalent interaction between the molecule and the surface. Based on the Bader analysis, the NO molecule acts as an acceptor to  $\alpha$ -PC and as a donor to  $\beta$ -PC. Particularly, a large amount ( $0.200 e$ ) of charge transferred from the  $\alpha$ -PC surface to the NO molecule and tiny charge transfer ( $0.058 e$ ) from the NO molecule to the  $\beta$ -PC surface were found. Interestingly, that NO has been predicted to be an acceptor on phosphorene<sup>22</sup> similarly to the case of  $\alpha$ -PC, while on graphene<sup>50</sup> NO is a donor similarly to the case of  $\beta$ -PC.

The LDOS analysis for the NO-adsorbed  $\alpha$ -PC surface, presented in Fig. 3b, depicted the half-filled doubly degenerated  $2\pi$  frontier and  $5\sigma$  and  $1\pi$  spin-split orbitals of NO. Such an orbital hybridization of NO with phosphorus orbitals allows strong charge transfer between the molecule and the surface as confirmed by the Bader analysis. According to the band structure (Fig. 3a, right panel), the singly occupied HOMO state of NO is below the Fermi level and the conduction band minimum (CBM) shifts closer to the Fermi level signifying enhanced interaction on the molecule and the surface. The workfunction of the  $\alpha$ -PC surface adsorbed with the NO molecule decreases from 4.87 to 4.63 eV. The LDOS (Fig. 3c) and the band structure (Fig. 3c, right panel) plots of the NO-adsorbed  $\beta$ -PC show additional molecule-induced states in the vicinity of CBM. The fundamental band gap of  $\beta$ -PC remains unchanged (Table 2) and the workfunction decreases from 4.95 to 4.84 eV.

### NO<sub>2</sub> adsorption

Among all the considered molecules NO<sub>2</sub> has the strongest adsorption ability to  $\alpha$ - and  $\beta$ -PC. The molecule occupies the position at  $d = 1.67$  ( $\alpha$ -PC) and  $d = 1.38$  ( $\beta$ -PC) Å above the C–P bond with two O atoms directed to the surface plane. In both cases (Fig. 4a and c, left panel), the N–O bond located closer to the surface is significantly elongated (up to 1.40 Å) compared to that of a free NO<sub>2</sub> gas molecule (1.20 Å). The adsorption energy of NO<sub>2</sub> on  $\alpha$ -PC ( $E_a = -0.73$  eV) is lower than that of graphene ( $E_a = -0.67$  eV)<sup>50</sup> and that of phosphorene ( $E_a = -0.50$  eV),<sup>22,42</sup>



**Fig. 4** (a) Left panel: The top and side views of the lowest-energy configuration integrated with the total electron density plots for NO<sub>2</sub>-adsorbed  $\alpha$ -PC. Right panel: The band structure of NO<sub>2</sub>-adsorbed  $\alpha$ -PC. (b) The LDOS of NO<sub>2</sub>-adsorbed  $\alpha$ -PC. (c) Left panel: The top and side views of the lowest-energy configuration integrated with the total electron density plots for NO<sub>2</sub>-adsorbed  $\beta$ -PC. Right panel: The band structure of NO<sub>2</sub>-adsorbed  $\beta$ -PC. (d) The LDOS of NO<sub>2</sub>-adsorbed  $\beta$ -PC. The blue line shows the Fermi level. The isosurface value is set to  $0.05 e \text{ \AA}^{-3}$ . The bands and DOS coloured in red correspond to the NO<sub>2</sub> molecule.

while for  $\beta$ -PC the  $E_a = -0.59$  is almost equal to that of phosphorene.

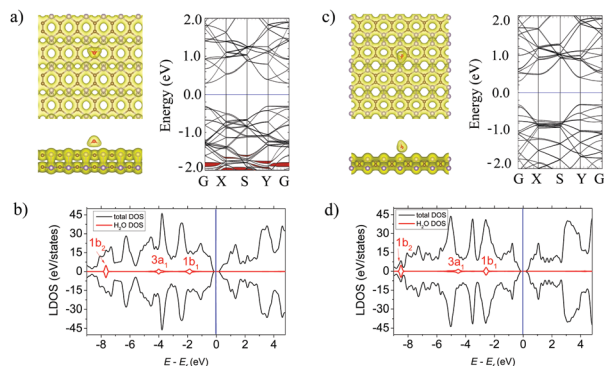
The strong molecule–surface interaction was also confirmed by the total electron density plot for the NO<sub>2</sub>-adsorbed  $\alpha$ - and  $\beta$ -PC surfaces (Fig. 4a and c, left panel). The NO<sub>2</sub> molecule tends to form a covalent bond with the nearest P atom on both the  $\alpha$ - and  $\beta$ -PC surfaces. Moreover, as it is shown in the insets of Fig. 4a and c (see the green circle in left panel), the P atom bonded to the molecule is lifted from the surface due to the interaction with the molecule, which suggests significant distortion of the surface in the contact area. The NO<sub>2</sub> molecule was found to be a strong acceptor to both  $\alpha$ - and  $\beta$ -PC. The Bader analysis revealed a giant charge transfer of 1.023 and 1.013  $e$  from the molecule to the  $\alpha$ - and  $\beta$ -PC surfaces, respectively.

The LDOS graphs of NO<sub>2</sub>-adsorbed  $\alpha$ - and  $\beta$ -PC surfaces are presented in Fig. 4b and d, respectively. Both results indicate that the  $6a_1$  orbital is split into two levels, while all other orbitals are significantly broadened and coincide with the states of the host material. Such mixing and hybridization of NO<sub>2</sub> orbitals explain the facilitated charge transfer between the molecule and the  $\alpha$ - and  $\beta$ -PC surfaces. The band structure analysis (Fig. 4a and c, right panel) uncovered the effect of atomic disorders induced by NO<sub>2</sub> adsorption on the bands' alignment of the host material. More specifically, the structural transformation induces localized states originated from the lifted P atom within the fundamental band gap of the host materials. The workfunction of NO<sub>2</sub>-adsorbed  $\alpha$ -PC increases from 4.95 to 5.07 eV, while in case of  $\beta$ -PC the workfunction decreases to 4.61 eV (Table 2), which can be explained by a large impact of the defect states in the VBM of the host material.

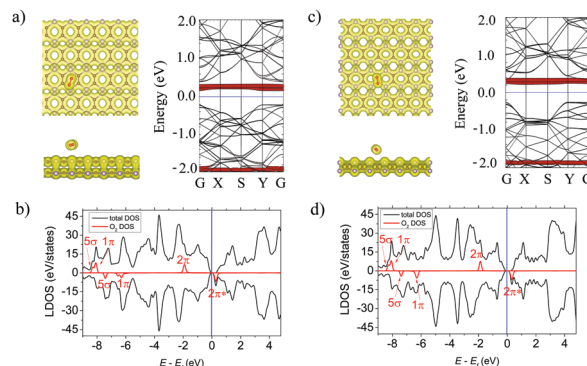
### H<sub>2</sub>O adsorption

The H<sub>2</sub>O molecule is adsorbed at  $d = 1.77$  Å above the  $\alpha$ -PC surface and is located above the P–P bond with two H–O bonds





**Fig. 5** (a) Left panel: The top and side views of the lowest-energy configuration integrated with the total electron density plots for H<sub>2</sub>O-adsorbed  $\alpha$ -PC. Right panel: The band structure of H<sub>2</sub>O-adsorbed  $\alpha$ -PC. (b) The LDOS of H<sub>2</sub>O-adsorbed  $\alpha$ -PC. (c) Left panel: The top and side views of the lowest-energy configuration integrated with the total electron density plots for H<sub>2</sub>O-adsorbed  $\beta$ -PC. Right panel: The band structure of H<sub>2</sub>O-adsorbed  $\beta$ -PC. (d) The LDOS of H<sub>2</sub>O-adsorbed  $\beta$ -PC. The blue line shows the Fermi level. The isosurface value is set to  $0.05 \text{ e} \text{ \AA}^{-3}$ . The bands and DOS coloured in red correspond to the H<sub>2</sub>O molecule.



**Fig. 6** (a) Left panel: The top and side views of the lowest-energy configuration integrated with the total electron density plots for O<sub>2</sub>-adsorbed  $\alpha$ -PC. Right panel: The band structure of O<sub>2</sub>-adsorbed  $\alpha$ -PC. (b) The LDOS of O<sub>2</sub>-adsorbed  $\alpha$ -PC. (c) Left panel: The top and side views of the lowest-energy configuration integrated with the total electron density plots for O<sub>2</sub>-adsorbed  $\beta$ -PC. Right panel: The band structure of O<sub>2</sub>-adsorbed  $\beta$ -PC. (d) The LDOS of O<sub>2</sub>-adsorbed  $\beta$ -PC. The blue line is showing the Fermi level. The isosurface value is set to  $0.05 \text{ e} \text{ \AA}^{-3}$ . The bands and DOS coloured in red correspond to the O<sub>2</sub> molecule.

directed to the surface. In case of  $\beta$ -PC, the molecule is located so that the H atom's position is at  $d = 2.92 \text{ \AA}$  above the center of the hollow hexagon, one H–O bond is tilted away from the surface and one H–O bond is almost perpendicular to the surface plane (Fig. 5a, left panel). The adsorption energy of H<sub>2</sub>O on  $\alpha$ -PC ( $E_a = -0.24 \text{ eV}$ ) and  $\beta$ -PC ( $E_a = -0.31 \text{ eV}$ ) is about 2 times lower than that of phosphorene ( $E_a = -0.14 \text{ eV}$ )<sup>22</sup> and almost the same as that of graphene ( $E_a = -0.27 \text{ eV}$ ).<sup>50</sup>

The noncovalent bond between H<sub>2</sub>O and the  $\alpha$ - and  $\beta$ -PC surfaces is predicted by a zero-electron density at the interface region as shown in Fig. 5a and c, left panel. A comparably weak interaction of H<sub>2</sub>O with  $\alpha$ - and  $\beta$ -PC was also confirmed by the Bader analysis which differentiate the low charge transfer of  $0.038$  ( $\alpha$ -PC) and  $0.026 e$  ( $\beta$ -PC) from the surface to the molecule.

Based on the LDOS plots in Fig. 5b and d, the  $3a_1$  highest occupied molecular orbital of H<sub>2</sub>O is greatly broadened and has the largest orbital mixing with the states of the host material, which responsible for the charge transfer between the molecule and the  $\alpha$ - and  $\beta$ -PC surfaces. According to Fig. 5a and c, right panel, similarly to graphene<sup>50</sup> and phosphorene,<sup>22</sup>  $\alpha$ - and  $\beta$ -PC has no localized states originating from H<sub>2</sub>O within the fundamental band gap. In addition, the workfunction of H<sub>2</sub>O-adsorbed  $\alpha$ -PC ( $4.87 \text{ eV}$ ) is equal to that of pure PC ( $4.87 \text{ eV}$ ), while the workfunction of  $\beta$ -PC increases from  $4.95$  to  $5.13 \text{ eV}$  upon the H<sub>2</sub>O adsorption.

### O<sub>2</sub> adsorption

The O–O bond of the oxygen molecule is forming an angle of around  $30^\circ$  with the surface and is located at  $d = 2.87 \text{ \AA}$  above the center of the hollow hexagon for the  $\alpha$ -PC. The O–O bond increases from  $1.22 \text{ \AA}$  (for a free O<sub>2</sub> molecule) to  $1.24 \text{ \AA}$ . The  $E_a$  of the O<sub>2</sub> molecule on  $\alpha$ -PC is  $-0.59 \text{ eV}$  which is about 12 times lower than that of graphene ( $E_a = -0.04 \text{ eV}$ )<sup>52</sup> and about 2 times lower than that of phosphorene ( $E_a = -0.27 \text{ eV}$ ).<sup>21</sup> On the  $\beta$ -PC surface, the O<sub>2</sub> molecule adopts tilted position with the O–O

bond located at  $d = 2.21 \text{ \AA}$  above the P–P bond. The  $E_a = -0.18 \text{ eV}$  of the O<sub>2</sub> molecule on  $\beta$ -PC is about 4 times lower than that of graphene ( $E_a = -0.04 \text{ eV}$ )<sup>52</sup> but larger than that of phosphorene ( $E_a = -0.27 \text{ eV}$ ).<sup>22</sup>

The isosurface plots in Fig. 6a and c, left panel show noncovalent bonding between O<sub>2</sub> and both  $\alpha$ - and  $\beta$ -PC. The Bader analysis showed an acceptor role of the O<sub>2</sub> molecule for both  $\alpha$ - and  $\beta$ -PC with the amount of charge transferred of  $0.075$  and  $0.067 e$ , respectively. The LDOS (Fig. 6b and d) and band structure (Fig. 6a and c) reflect the half-filled  $2\pi$  state of O<sub>2</sub> within the band gap of both  $\alpha$ - and  $\beta$ -PC.

It worth noting that predicted here non-covalent interaction of O<sub>2</sub> with  $\alpha$ - and  $\beta$ -PC suggests the molecule is physisorbed on the PC surfaces. For the phosphorene, it has been shown that O<sub>2</sub> can be chemisorbed if the energy barrier is overcome.<sup>7</sup> The energy barrier and the detailed pathway from the initial state (IS), to the transition state (TS) and to the final state (FS) for oxidation of  $\alpha$ - and  $\beta$ -PC by O<sub>2</sub> are shown in Fig. S6 (ESI<sup>†</sup>). The calculated energy barriers for  $\alpha$ - and  $\beta$ -PC are  $0.29$  and  $0.59 \text{ eV}$ , respectively. Therefore, the O<sub>2</sub> molecule may experience an energy barrier from the physisorption to chemisorption on the PC surface. Based on this, PC is considered to behave similarly to antimonene where oxygen species preferably attached above the surface.<sup>53</sup> To investigate the joint effect of water and oxygen<sup>54</sup> on the structural stability of  $\alpha$ - and  $\beta$ -PC, the *ab initio* molecular dynamics simulations at room temperature ( $300 \text{ K}$ ) are performed. The simulated snapshots in Fig. S7 and Movies S1, S2 (ESI<sup>†</sup>) show the H<sub>2</sub>O molecule, initially placed in close contact with the O species on the pre-oxidized  $\alpha$ - and  $\beta$ -PC surfaces, randomly walks above the surface. This suggests high resistance of  $\alpha$ - and  $\beta$ -PC to H<sub>2</sub>O and explains their stability under the environment conditions.<sup>55,56</sup>

### Potentials in gas censoring

It is found that NH<sub>3</sub>, H<sub>2</sub>O and O<sub>2</sub> are physisorbed on  $\alpha$ - and  $\beta$ -PC surfaces. Importantly, as it has been found for



phosphorene,<sup>22,42</sup> the adsorbed O<sub>2</sub> molecule also induces partially occupied states within the band gap of  $\alpha$ - and  $\beta$ -PC, which facilitates the creation of recombination centers for excitons in PC.

The NO molecule forms a covalent bond with the  $\alpha$ -PC surface, while noncovalent bonding is typical for the  $\beta$ -PC surface. This significantly modifies the band structure of NO-adsorbed PC. Particularly, chemisorbed NO induces unoccupied states below the Fermi level and within the band gap of  $\alpha$ -PC, while NO physisorbed on  $\beta$ -PC induces partially unoccupied states above the Fermi level and within the band gap. This also explains the acceptor role of NO on  $\alpha$ -PC and donor nature on  $\beta$ -PC. Non-trivial adsorption behaviour of NO on  $\alpha$ - and  $\beta$ -PC can be attributed to the different mechanisms of the interaction of the molecule with surfaces of different phases. The sp<sup>3</sup> bonding of phosphorus atom in  $\alpha$ -PC allows a covalent interaction of NO with the surface, as confirmed by a strong mixing of NO states with the 3s states of phosphorus atom. In turn, the sp<sup>2</sup> bonding between carbon atoms in  $\beta$ -PC weakens the interaction of NO with the surface.

The NO<sub>2</sub> molecule has the strongest effect on the structure and properties of  $\alpha$ - and  $\beta$ -PC. Its chemisorption on the PC surface accounts for the local distortions in the contact area between the molecule and the surface. These distortions are responsible for the formation of the defect on the PC surface. The defect induces localized states within the band gap of  $\alpha$ - and  $\beta$ -PC is responsible for the giant charge transfer from the surface to NO<sub>2</sub> and splitting and hybridization of NO<sub>2</sub> orbitals. Noticeably, NO<sub>2</sub> is a more oxidative species compared to the other studied molecules due to the high chemical states of the nitrogen. Similar phenomenal absorption of the NO<sub>2</sub> molecule is predicted for C<sub>3</sub>N monolayer.<sup>57</sup> This explains the strongest adsorption ability of NO<sub>2</sub> compared to other considered molecules.

In addition, adsorption of NO<sub>2</sub> and O<sub>2</sub> on  $\alpha$ -PC and H<sub>2</sub>O on  $\beta$ -PC increases their workfunction, while in other cases the workfunction of  $\alpha$ - and  $\beta$ -PC slightly decreases or remains unchanged. Fig. 7 shows the comparison of the adsorption energies of the considered molecules on  $\alpha$ - and  $\beta$ -PC and graphene and phosphorene. It can be concluded that the obtained results indicate the advantage of  $\alpha$ - and  $\beta$ -PC over graphene and phosphorene in terms of sensitivity to NH<sub>3</sub>, NO, NO<sub>2</sub>, H<sub>2</sub>O, and O<sub>2</sub> molecules. This is mostly due to the different bonding nature in graphene, phosphorene and PC.<sup>38,58</sup> The case study on that is discussed in ESI† and is presented in Fig. S8 (ESI†).

## Conclusions

Our work predicts high sensitivity of  $\alpha$ - and  $\beta$ -PC to the most common environmental molecules which open up possibilities of fabrication of PC-based gas sensor devices. The remarkable transfer of electrons between PC and NO, NO<sub>2</sub>, and O<sub>2</sub> suggests molecular adsorption as a useful tool for tuning the carrier density of PC. In addition, the Raman spectroscopy has shown that the strength of interatomic bonds can be altered in graphene and phosphorene due to the charge flow induced by environmental molecules.<sup>22,59</sup> Our results on NO<sub>2</sub> adsorption show that the charge transfer between environmental molecules and  $\alpha$ - and  $\beta$ -PC can also alter the strength of its bonds. Moreover, the observed modification in the band structure of  $\alpha$ - and  $\beta$ -PC upon physisorption of environmental molecules make the use of photoluminescence or current flow possible as a detection tool. It is important to note, that the surface coverage of PC by environmental molecules may cause a decrease of its workfunction, which in turn could affect the charge injection from the electrode to the channel layer and, consequently, the performance of PC-based devices.

## Conflicts of interest

There are no conflicts to declare.

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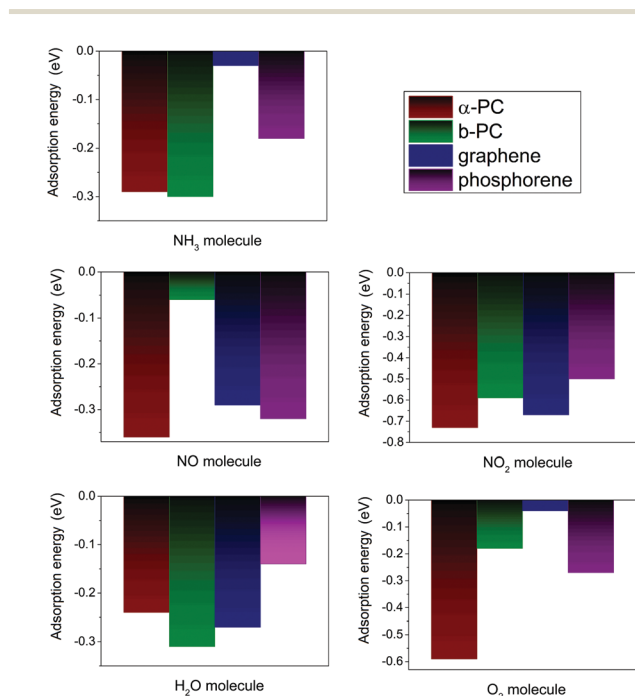


Fig. 7 The comparison of the adsorption energy of NH<sub>3</sub>, NO, NO<sub>2</sub>, H<sub>2</sub>O, and O<sub>2</sub> on  $\alpha$ - and  $\beta$ -PC and graphene<sup>50,51</sup> and phosphorene.<sup>20,22,49</sup>



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